MSKSEMI 美森科













ESD

TSS

MOV

GDT

PIFD

L7809CV(MS)

Product specification





Three-terminal positive voltage regulator

FEATURES

Maximum Output current IOM: 1.5A

Output voltage Vo: 9V

Continuous total dissipation

P_D: 1.5 W (T_a = 25 °C) 15 W(T_c = 25 °C)

Reference News

PACKAGE OUTLINE		Marking
1 2 3	1.IN 2.GND 3.OUT	MSKSEMI L7809CV CHN MS**

ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

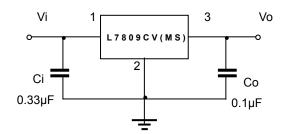
Parameter	Symbol	Value	Unit
Input Voltage	V _i	35	V
Thermal Resistance from Junction to Ambient	R _{θJA}	83.3	°C/W
Thermal Resistance from Junction to Case	R _{eJC}	8.3	°C/W
Operating Junction Temperature Range	T _{OPR}	0~+150	${\mathfrak C}$
Storage Temperature Range	T _{STG}	-55~+150	°C

ELECTRICAL CHARACTERISTICS AT SPECIFIED VIRTUAL JINCTION TEMPERATURE

(Vi=16V, Io=500mA,Ci=0.33 μ F,Co=0.1 μ F, unless otherwise specified)

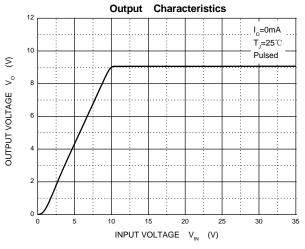
Parameter	Symbol	Test conditions		MIN	TYP	MAX	UNIT
			25℃	8.65	9	9.35	V
Output voltage	Vo	11.5V≤V _i ≤24V, lo= 5mA-1A, P≤15W	0-125℃	8.55	9	9.45	V
Load Regulation	1)/0	Io=5mA-1.5A	25℃		12	180	mV
	ΔVo	lo=250mA-750mA	25℃		4	90	mV
Line regulation	4)/0	11.5V≤V i≤27V	25℃		7	180	mV
	ΔVo	13V≤V _i ≤19V	25℃		2	90	mV
Quiescent Current	Iq		25℃		4.3	8	mA
Quiescent Current Change	Δlq	11.5V≤V _i ≤27V	0-125℃			1	mA
		5mA≤I _O ≤1A	0-125℃			0.5	mA
Output voltage drift	△Vo/△T	I _O =5mA	0-125℃		-1		mV/℃
Output Noise Voltage	V _N	10Hz≤f≤100KHz	25℃		60		uV
Ripple Rejection	RR	12V≤V _i ≤22V,f=120Hz	0-125℃	55	70		dB
Dropout Voltage	Vd	Io=1A	25℃		2		V
Output resistance	Ro	f=1KH _Z	25℃		18		mΩ
Short Circuit Current	Isc		25℃		400		mA
Peak Current	lpk		25℃		2.0		Α

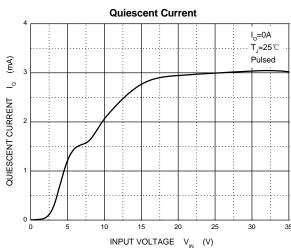
TYPICAL APPLICATION

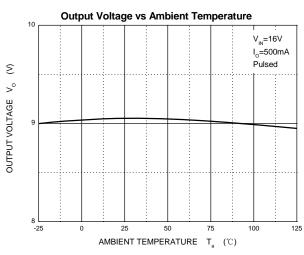


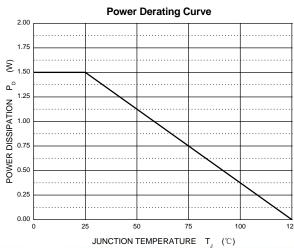


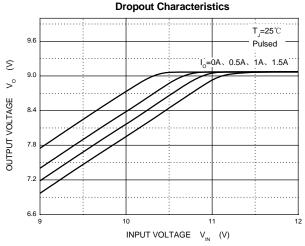
Typical Characterisitics

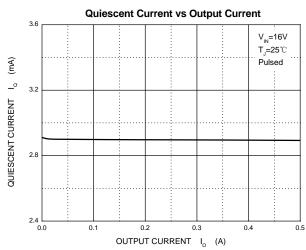


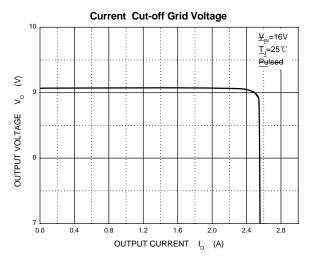






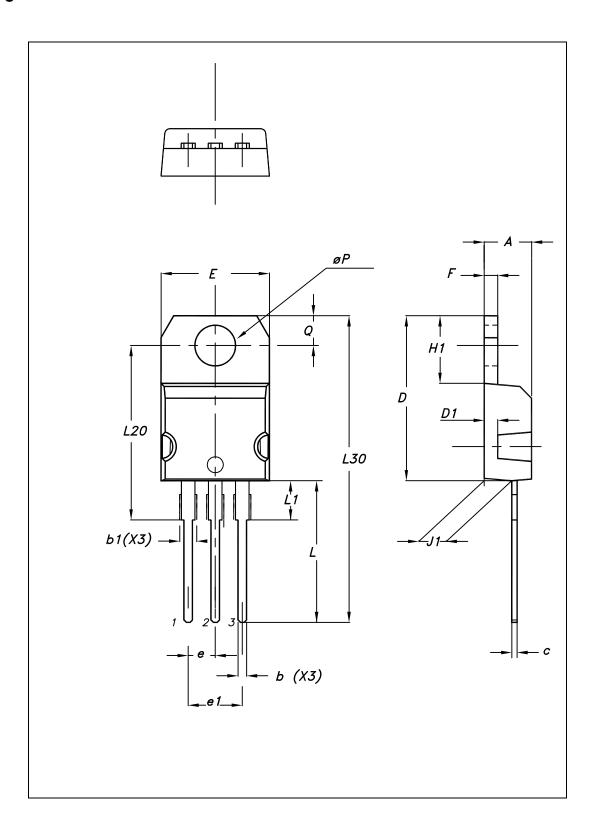








Package mechanical data





Package mechanical data

D:		mm				
Dim.	Min.	Тур.	Max.			
А	4.40		4.60			
b	0.61		0.88			
b1	1.14		1.70			
С	0.48		0.70			
D	15.25		15.75			
D1		1.27				
E	10		10.40			
е	2.40		2.70			
e1	4.95		5.15			
F	1.23		1.32			
H1	6.20		6.60			
J1	2.40		2.72			
L	13		14			
L1	3.50		3.93			
L20		16.40				
L30		28.90				
ØP	3.75		3.85			
Q	2.65		2.95			

REEL SPECIFICATION

P/N	PKG	QTY
L7809CV(MS)	TO-220	50/One tube 1000/a box of



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